

# **Ultra-Low Jitter Crystal Oscillators (XO)**

### **Features**

- Available at any frequency from 10 MHz to 1000 MHz
- Ultra-Low Jitter (12 KHz to 20 MHz)
  - 32 fs at 312.50 MHz
  - 34 fs at 491.52 MHz
- Total stability of ±20 ppm
- CML/LVDS/LVPECL/HCSL output formats
- Output Enable/Disable Feature
- < 10 ms start-up time
- No activity dips or micro jumps
- Industry standard 2.5X2.0 mm 6-pin LGA package
- Single 1.8V supply with internal regulator
- Superior power supply immunity
- Temperature range: -40°C to 85°C
- Temperature extended range: -40°C to 105°C
- ESD HBM 2000V, CDM 500V
- Lead free / RoHS compliant

### Applications

- Network Equipment (Optical Modules, routers)
- 100G/200G/400G/800G OTN, Coherent optics
- Storage, switches, servers, NICs, accelerators
- Datacenter
- 3G to 24G SDI broadcast video
- 10G/40G/100G optical ethernet
- 56G/112G PAM4 Clocking
- Test and measurement equipment



# **General Description**

The MS1130 is a crystal oscillator (XO) powered by our Virtual Crystal<sup>™</sup> technology that enables very stable fully programmable multi-GHz clocks with extremely low phase noise.

Adaptive fully autonomous DSP algorithms running in the background continuously monitor and ensure robust and consistent performance over process, voltage and temperature variations.

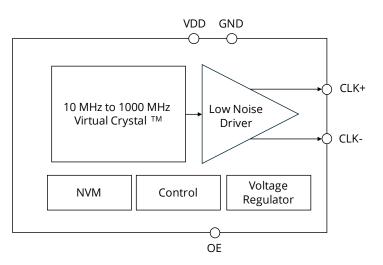
The devices are factory programmed to provide any frequency between 10 MHz and 1000 MHz with less than 1 ppb resolution.

The MS1130 is manufactured in a high-volume 28 nm CMOS process and represents the most advanced node in the timing industry.

### **Device Information**

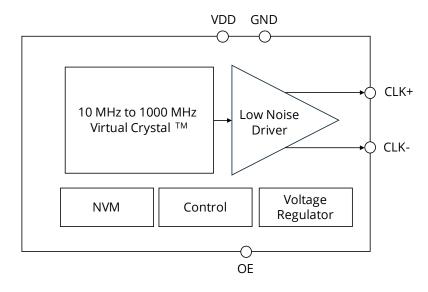
Part Number	Package	Description
MS1130	2.5x2.0 mm 6-pin LGA	Single frequency

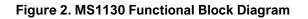
### Figure 1. Functional Block Diagram



# MS1130

### **Single Frequency Device**





### **Pin Assignment and Pin Description**

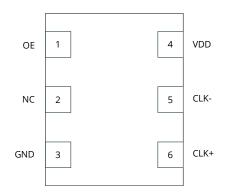




Table 1. MS1130 Pin Description
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Pin No	Name	Description			
1	OE	Output Enable			
2	NC	No Connect			
3	GND	Ground			
4	CLK+	Clock Output			
5	CLK-	Complementary Clock Output			
6	VDD	Power Supply			

# Specifications

#### **Table 2. Electrical Specifications**

Typical values are specified at  $T_A$ = 25°C,  $V_{DD}$ =1.8V unless otherwise specified. All Min and Max limits are specified over the operating temperature range and voltage range with standard termination. A 0.1µF and 10µf bypass capacitor should be connected between VDD and GND pins located close to the device.

Parameter Symbol	Test Condition/Comment	Min	Тур	Max	Unit
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#### **Frequency Range**

Frequency Range	Fclk	All Output Formats	10	1000	MHz

#### **Frequency Stability**

Frequency Stability*	F <sub>STB</sub>	-40°C to 85°C	-20		20	PPM	
Frequency Stability*	FSTB	-40°C to 105°C	-25		25	PPM	
*Frequency stability includes initial tolerance, voltage tolerance, operating temperature and aging (10 year, +25°C). Aging is estimated from environmental reliability tests;							

#### **Clock Output Jitter Characteristics**

RMS Phase Jitter (12 KHz – 20 MHz)	Φjitter	Frequency=312.5 MHz		32		fs	
Note:							
Phase jitter measured	Phase jitter measured on Agilent 5052B Signal Source Analyzer						

#### **Operating Voltage/Temperature Range**

Supply Voltage	V <sub>DD</sub>		1.71	1.8	1.89	V
	_	Industrial Temperature	-40		85	°C
Temperature Range	TA	Extended Industrial Temperature	-40		105	°C

### **Current Consumption**

		LVDS Output	80	100	mA
Supply Current	I <sub>dd</sub>	(Output Enabled)			
		All Other Outputs	90	110	mA
		(Output Enabled)	00		
		Tristate Hi-Z	50	60	mA
		(Output Disabled)	50	00	

#### **Input Characteristics**

Digital Input Levels	VIH		0.7XV <sub>DD</sub>			V
(OE)	VIL			0.32	XV <sub>DD</sub>	V
Output Enable (OE)	T⊳	Output Disable Time			3	us
	Τ <sub>Ε</sub>	Output Enable Time		2	20	us
Powerup Time	T <sub>PWR</sub>	Time from 0.9xVDD until output frequency (F <sub>CLK</sub> ) within spec		1	10	ms

#### **PSRR Characteristics**

Note:				
PSRR	PSRRspur	Spurs induced by 50mV power supply ripples (All frequency, all output types)	-100	dBc

(1) Measured maximum spur level with 50mVpp sinusoidal signal between 50 kHz and 1 MHz applied on VDD Pin

Output Duty Cycle	DC	All Output Formats	48		52	%
Output Rise/Fall Time (20% to 80% V <sub>PP</sub> )	T <sub>R</sub> / T <sub>F</sub>	All Output Formats		65	100	ps
LVDS Output (AC Mode)	Vo	Swing (Diff)	0.5	0.7	0.9	V
LVDS Extended Output (AC Mode)	Vo	Swing (Diff)	0.8	1.2	1.6	V
CML Output (AC Mode)	Vo	Swing (Diff)	0.7	0.85	1	V
LVPECL Output (AC Mode) Integrated Termination	Vo	Swing (Diff)	1.2	1.4	1.6	V
HCSL Output Integrated Termination	Vo	Swing (Diff)	1.2	1.4	1.6	V

#### Output Characteristics

### Table 3. Absolute Maximum Ratings

Parameter	Min	Max	Unit
1.8V Supply Voltage	-0.3	1.98	V
Digital I/O	-0.3	1.98	V
Maximum Operating Temperature		105	°C
Storage Temperature	-55	150	°C
Soldering Temperature		260	°C
Junction Temperature		150	°C
Note: Stresses that exceed what is listed in this table may cause permanent damage to the device. Exposure to conditions above the			

Note: Stresses that exceed what is listed in this table may cause permanent damage to the device. Exposure to conditions above the recommendations for extended periods of time may affect device reliability.

#### Table 4. Environmental Compliance

Parameter	Test Condition
Mechanical Shock	MIL-STD-883, Method 2002
Mechanical Vibration	MIL-STD-883, Method 2007
Moisture Sensitivity Level (MSL)	3
Note: For additional information not listed, please contact Mixed-Signal Devices.	

#### Table 5. ESD Levels

Description	Description	Specification	Level
HBM <sup>1</sup>	Human Body Model	JEDEC JS-001	2000V
CDM <sup>2</sup>	Charge Device Model	JEDEC JESD22-C101	500V
Notes: 1. 1000V HBM allows safe manufacturing with standard ESD control process – JEDEC document JEP155 2. 250V CDM allows safe manufacturing with standard ESD control process – JEDEC document JEP157			

### Table 6. Package Thermal Information

Package	Parameter	Symbol	Value	Unit
Thermal Resistance, Junction to Ambient		Ø <sub>JA</sub>	90	°C/W
2.5mm x 2mm	Thermal Resistance, Junction to Board	ØJB	40	°C/W
6 pin LGA	S pin LGA Air Flow Condition		0	mps
	Maximum Junction Temperature			°C
Note: The thermal resistance information stated in this table is based on a standard JEDEC PCB condition. The actual thermal resistance varies depending on the customer PCB design.				

### **Table 7. Typical Output Phase Noise Characteristics**

VDD= 1.8V, T<sub>A</sub> = 25°C, Output Type = CML

Offset frequency	156.25 MHz	312.50 MHz	491.52 MHz	625.00 MHz	Unit
1 KHz	-107	-101	-96	-94	dBc/Hz
10 KHz	-136	-130	-126	-124	dBc/Hz
100 KHz	-156	-152	-148	-145	dBc/Hz
1 MHz	-165	-161	-156	-153	dBc/Hz
10 MHz	-166	-162	-157	-154	dBc/Hz
20 MHz	-166	-162	-157	-154	dBc/Hz
RMS Jitter (12 KHz – 20 MHz)	39.8 fs	31.9 fs	34.3 fs	38.2 fs	fs

# **Typical Output Measured Phase Noise Plots**

This section shows MS1130 performance plots.

Measurement parameters are: VDD = 1.8 V, TA = 25°C, Output Type = CML.

The plots were captured using an Agilent E5052B Signal Source Analyzer.

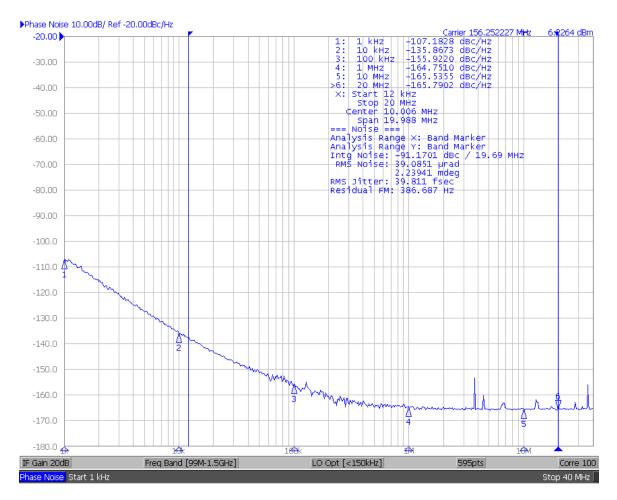


Figure 4. Carrier: 156.25 MHz

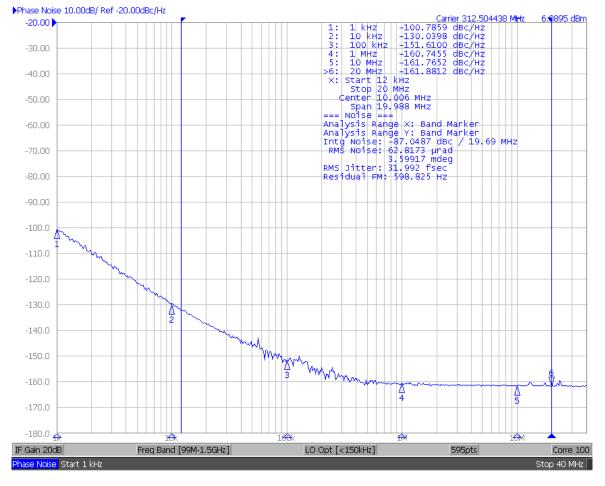


Figure 5. Carrier: 312.5 MHz

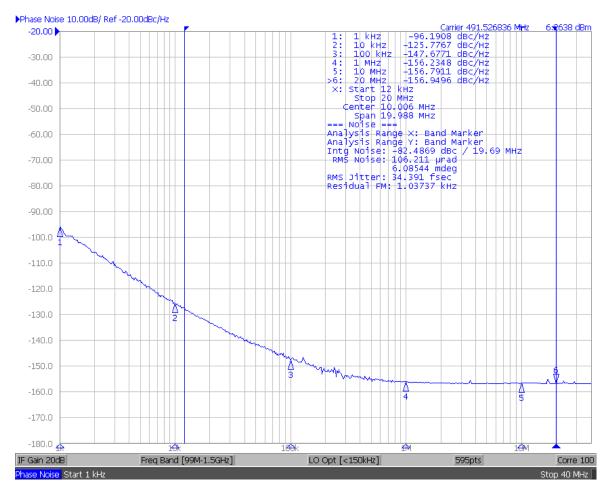


Figure 6. Carrier: 491.52 MHz

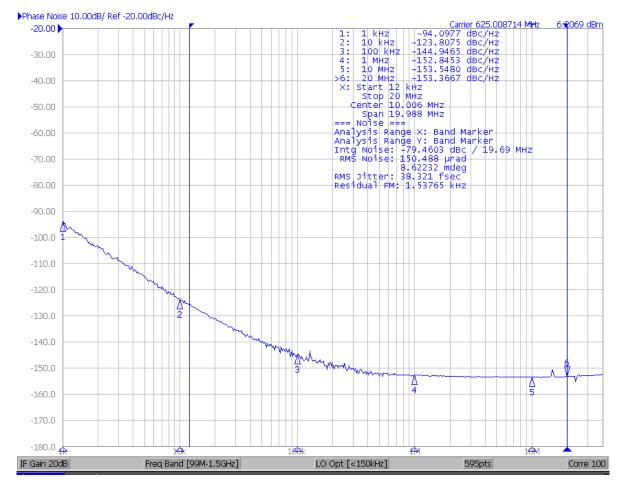


Figure 7. Carrier: 625 MHz

# **Output Terminations**

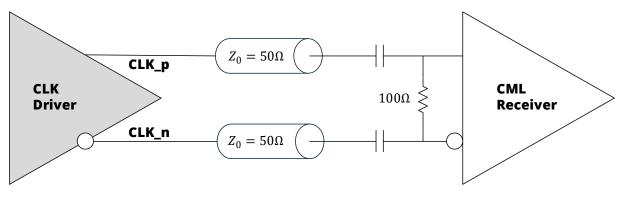


Figure 8. AC-Coupled CML

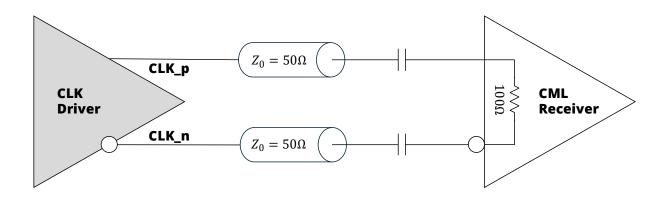


Figure 9. AC-Coupled CML (Receiver Termination)

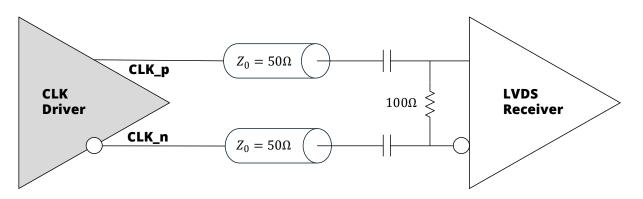


Figure 10. AC-Coupled LVDS

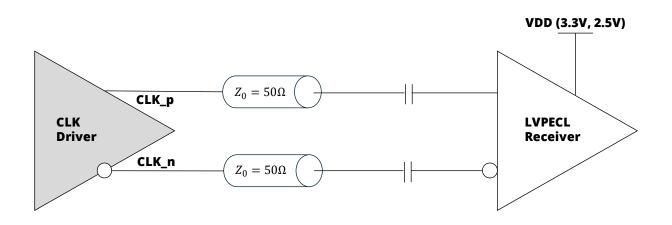


Figure 11. AC-Coupled LVPECL (Integrated Termination)

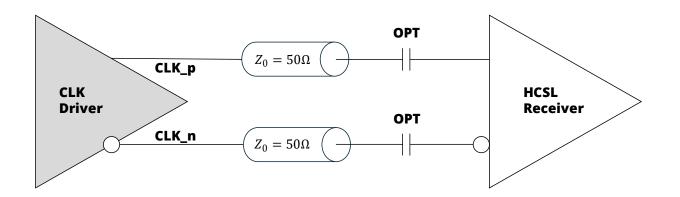
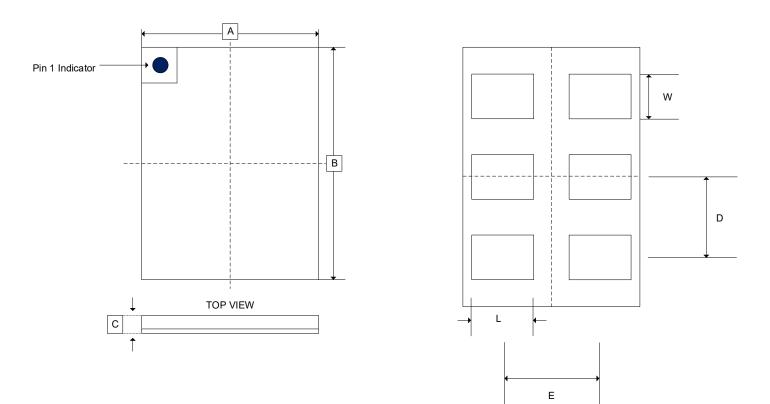


Figure 12. HCSL (Integrated Termination)

# **Packaging Information**

Figure 13 shows the MS1130 packaging drawing.



#### Figure 13. MS1130 Packaging Drawing (2.5X2.0 mm)

Table 8	. MS1130	Packaging	Dimensions
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Dimensions	Min	Nom	Max
A		2.00 BSC	
В		2.50 BSC	
С	0.903	0.96	1.1
L	0.55	0.60	0.65
W	0.35	0.40	0.45
D	0.85 BSC		
E	1 BSC		
Package Edge Tolerance	0.1		
Mold Flatness	0.2		
Coplanarity	0.08		

Note: All dimensions are in millimeters

# **Packaging Land Pattern**

Figure 14 shows the MS1130 PCB land pattern. Note: All dimensions are in millimeters

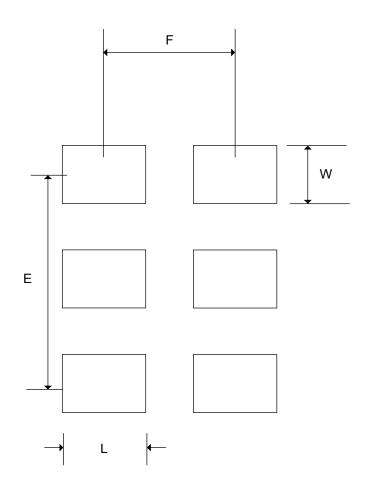




Table 9. MS1130 Packagir	ng Land Pattern Dimensions

Dimensions	Length
L	0.75
W	0.55
E	1.7
F	1

# **Device Top Marking**

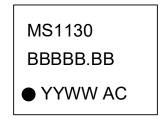


Figure 15. MS1130 Device Top Marking Showing Pin 1

Line	Position	on Description	
1	1	Product Marking	
2	1-5	Lot Number	
2	6-7	Wafer Number	
		Lot Trace Code	
	1	Pin 1 Orientation Mark (Dot)	
3	2-3	Year (last two digits of the year)	
	4-5	Calendar Work Week Number (1-53)	
	7-8	Assembly Code	

#### Table 10. MS1130 Device Marking Legend

# **Part Ordering Information**

Figure 16 shows a logic tree for ordering each of the available parts.

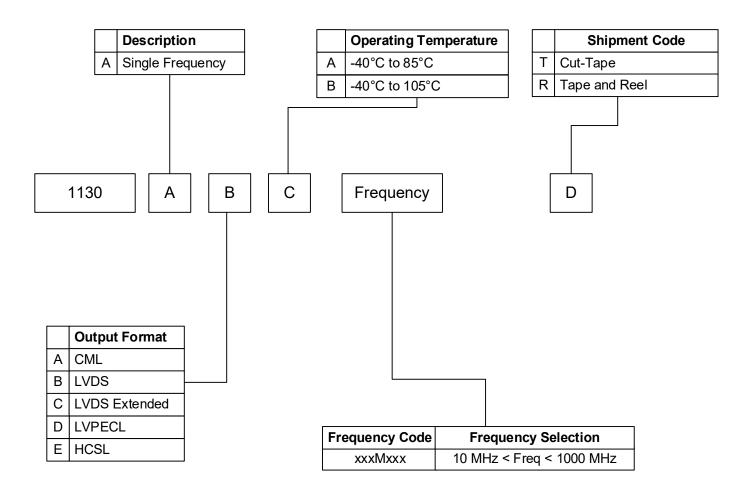


Figure 16. MS1130 Part Ordering Information

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